

March 2016

FDP51N25 / FDPF51N25 N-Channel UniFETTM MOSFET 250 V, 51 A, 60 m Ω

Features

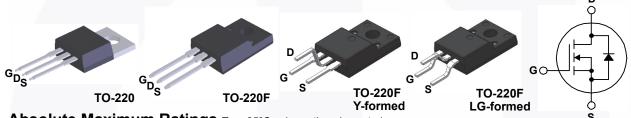
- $R_{DS(on)}$ = 48 $m\Omega(Typ.)$ @ V_{GS} = 10 V, I_D = 25.5 A
- Low Gate Charge (Typ. 55 nC)
- Low Crss (Typ. 63 pF)

Applications

- PDP TV
- Lighting
- · Uninterruptible Power Supply
- · AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Para	nmeter	FDP51N25	FDPF51N25 FDPF51N25YDTU FDPF51N25RDTU	Unit
V_{DSS}	Drain-Source Voltage			V	
I _D	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)	51 30	51* 30*	A A
I _{DM}	Drain Current	- Pulsed (Note 1)	204	204*	Α
V _{GSS}	Gate-Source voltage			V	
E _{AS}	Single Pulsed Avalanche Ene	ergy (Note 2)		mJ	
I _{AR}	Avalanche Current	(Note 1)		Α	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	32		mJ
V _{ISO}	Insulation withstand voltage external heat sink (t=0.3sec;	(RMS) from all three leads to $T_C = 25^{\circ}C$)	N/A	2500	V
dv/dt	Peak Diode Recovery dv/dt	(Note 3)		4.5	V/ns
P_D	Power Dissipation	(T _C = 25°C) - Derate Above 25°C	320 3.7	38 0.3	W W/°C
T _{J,} T _{STG}	Operating and Storage Temporary	erature Range	-55 to +150		°C
T _L	Maximum Lead Temperature 1/8" from Case for 5 Seconds	O .	300		°C

^{*}Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FDP51N25	FDPF51N25 FDPF51N25YDTU FDPF51N25RDTU	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.39	3.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDP51N25	FDP51N25	TO-220	Tube	N/A	N/A	50 units
FDPF51N25	FDPF51N25	TO-220F	Tube	N/A	N/A	50 units
FDPF51N25YDTU	FDPF51N25	TO-220F (Y-formed)	Tube	N/A	N/A	50 units
FDPF51N25RDTU	FDPF51N25	TO-220F (LG-formed)	Tube	N/A	N/A	50 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions		Тур.	Max.	Unit
Off Charac	teristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}, T_J = 25 ^{\circ}\text{C}$				V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.25		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 250 V, V _{GS} = 0 V V _{DS} = 200 V, T _C = 125°C			1 10	μ Α μ Α
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0V			-100	nA
On Charac	teristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 25.5 A		0.048	0.060	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 40 V, I _D = 25.5 A	\	43		S
Dynamic C	Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$		2620	3410	pF
C _{oss}	Output Capacitance	f = 1 MHz		530	690	pF
C _{rss}	Reverse Transfer Capacitance			63	90	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time	V_{DD} = 125 V, I_{D} = 51 A, V_{GS} = 10 V, R_{G} = 25 Ω		62	135	ns
t _r	Turn-On Rise Time			465	940	ns
t _{d(off)}	Turn-Off Delay Time		/	98	205	ns
t _f	Turn-Off Fall Time	(Note 4)		130	270	ns
Qg	Total Gate Charge	V _{DS} = 200 V, I _D = 51 A,		55	70	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V		16		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		27		nC
Drain-Sou	rce Diode Characteristics and Maximur	n Ratings				
I _S	Maximum Continuous Drain-Source Dio	de Forward Current			51	Α
I _{SM}	Maximum Pulsed Drain-Source Diode F	orward Current			204	Α
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 51 A			1.4	٧
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 51 A,		178		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100 A/μs		4.0		μС

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 0.68 mH, I $_{AS}$ = 51 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 Ω starting T $_{J}$ = 25° C. 3. I $_{SD}$ \leq 51 A, di/dt \leq 200 A/ μ s, V $_{DD}$ \leq BV $_{DSS}$, starting T $_{J}$ = 25° C.
- 4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

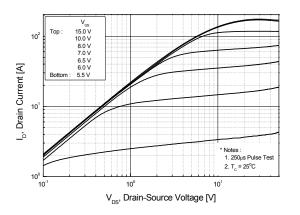


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

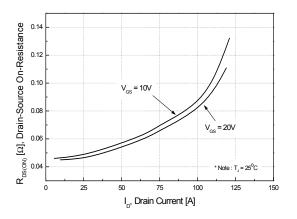


Figure 5. Capacitance Characteristics

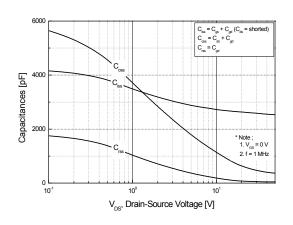


Figure 2. Transfer Characteristics

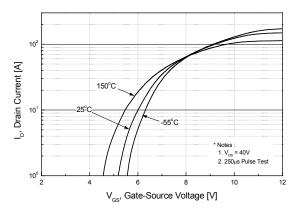


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperatue

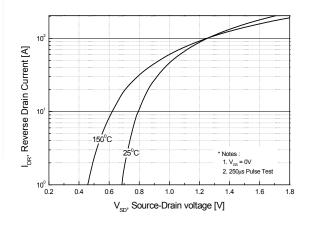
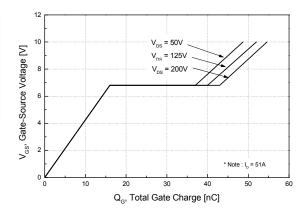


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

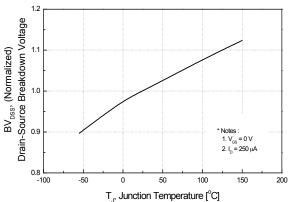


Figure 9-1. Maximum Safe Operating Area for FDP51N25



Figure 9-2. Maximum Safe Operating Area for FDPF51N25 / FDPF51N25YDTU

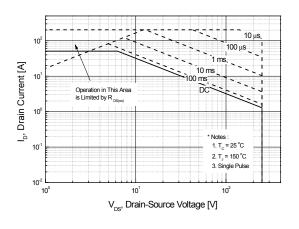
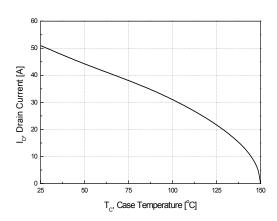


Figure 10. Maximum Drain Current vs. Case Temperature



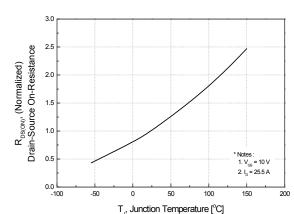
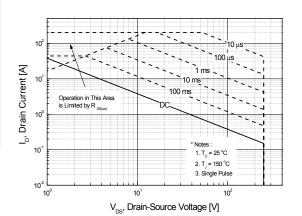


Figure 8. On-Resistance Variation

vs. Temperature



Typical Performance Characteristics (Continued)

Figure 11-1. Transient Thermal Response Curve for FDP51N25

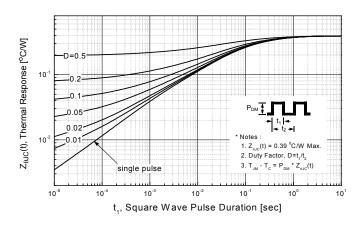
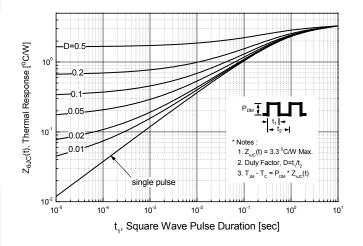


Figure 11-2. Transient Thermal Response Curve for FDPF51N25 / FDPF51N25YDTU



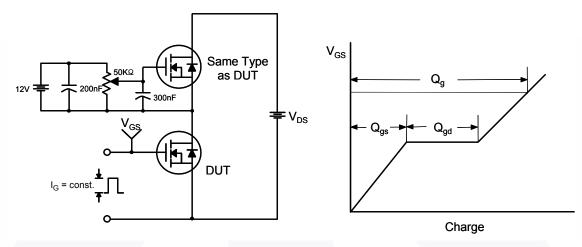


Figure 12. Gate Charge Test Circuit & Waveform

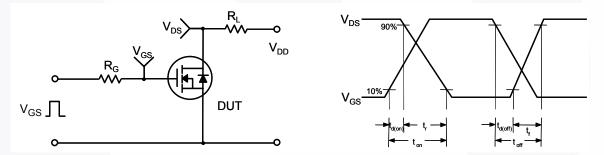


Figure 13. Resistive Switching Test Circuit & Waveforms

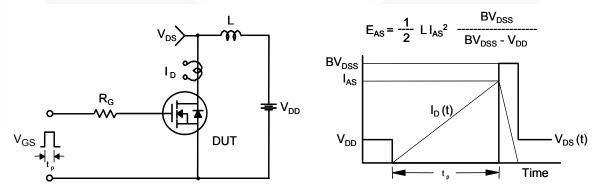


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

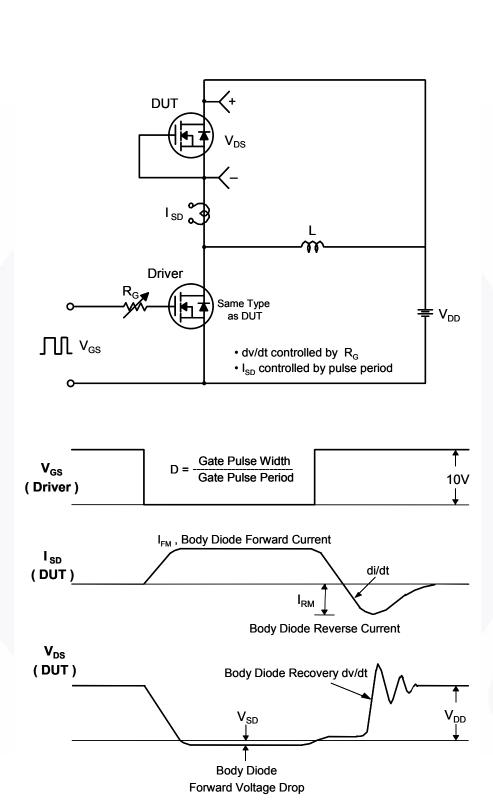
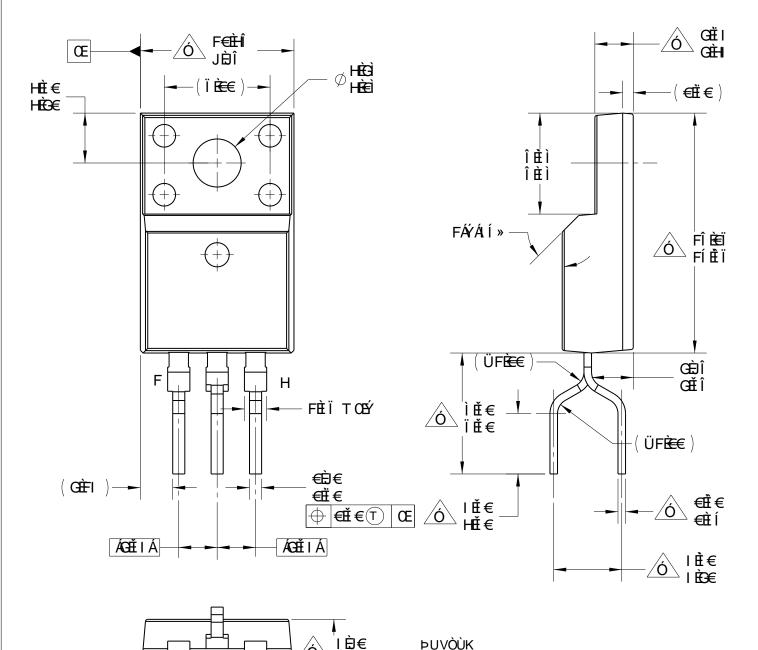


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

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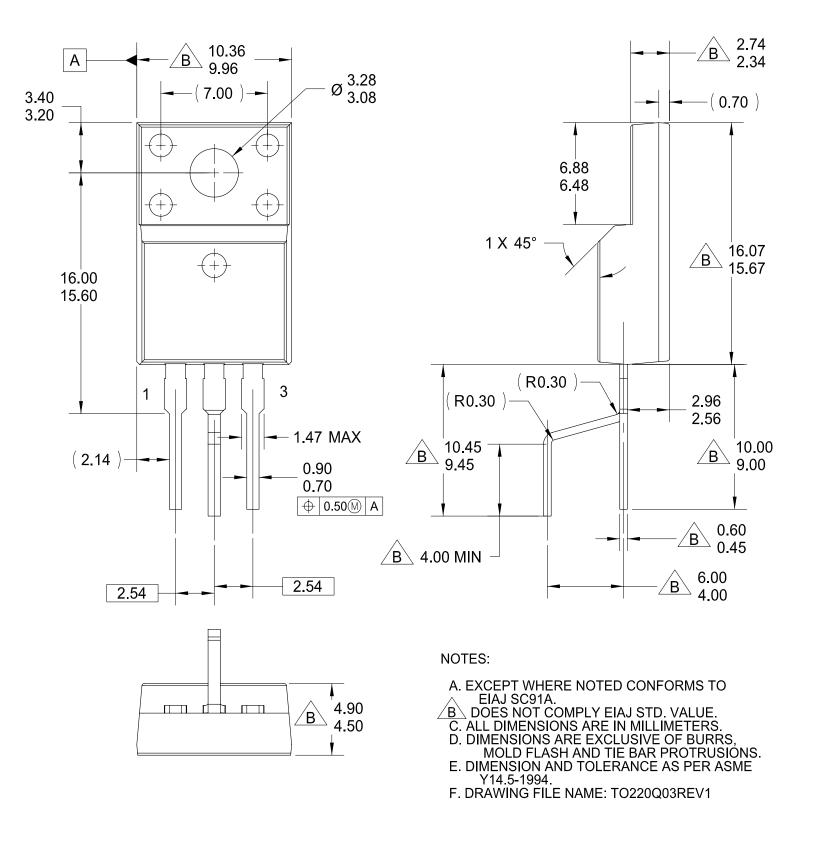
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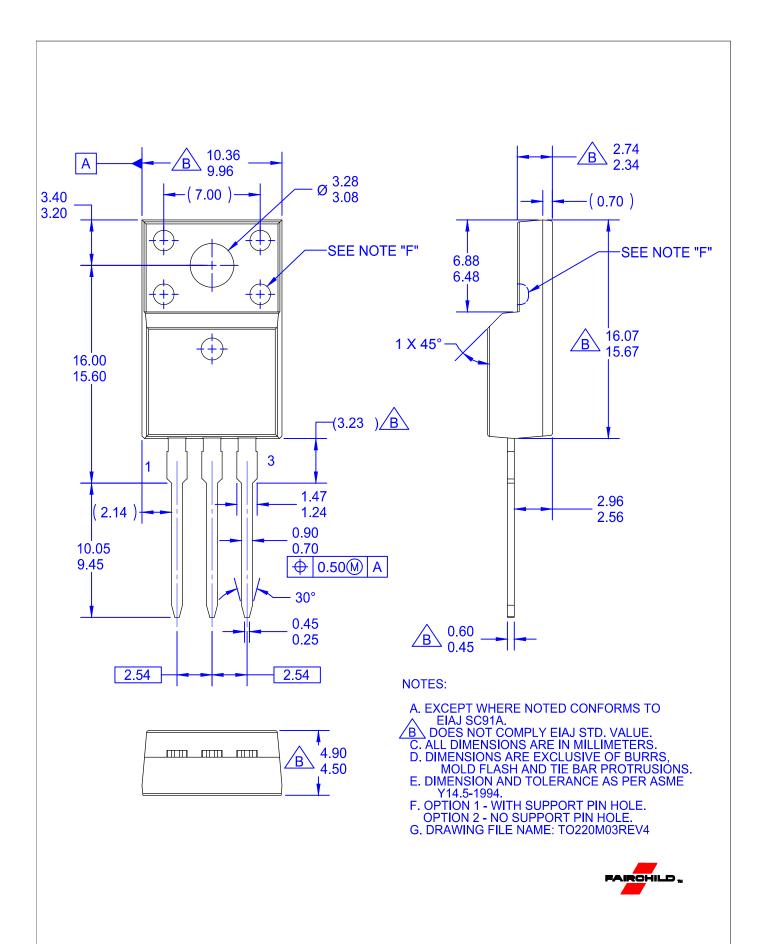
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Definition of Terms					
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